

SI3586DV-T1-E3

equest a Quote

SI3586DV-T1-E3 Information

www.bakener.com	Part Number	SI3586DV-T1-E3	
	Manufacturer	Vishay Siliconix	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays	
	Description	MOSFET N/P-CH 20V 2.9A 6TSOP	- 33
	Package	SOT-23-6 Thin, TSOT-23-6	- A
		For the pricing/inventory/lead time, please contact	
For Reference Only		us	
		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Red

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI3586DV-T1-E3 Specifications

Manufacturer Part Number	SI3586DV-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	N and P-Channel
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	2.9A, 2.1A
Rds On (Max) @ Id, Vgs	60 mOhm @ 3.4A, 4.5V
Vgs(th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	830mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-23-6 Thin, TSOT-23-6
Supplier Device Package	6-TSOP
	Report errors?

SI3586DV-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3586DV-T1-E3 Payment Methods



SI3586DV-T1-E3 Shipping Methods



If you have any question about SI3586DV-T1-E3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com